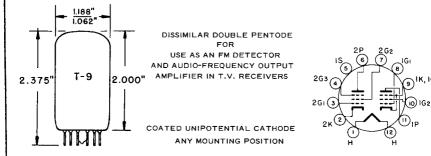
IK, IG3

TUNG-SOL -

DOUBLE PENTODE

COMPACTRON



GLASS BULB **BUTTON 12 PIN** BASE E12-70 OUTLINE DRAWING JEDEC 9-58

SECTION 1

BOTTOM VIEW BASING DIAGRAM JEDEC 12BU

THE 10AL11 IS A SHARP-CUTOFF, DUAL-CONTROL PENTODE AND A POWER PENTODE IN A T-9 COMPACTRON CONSTRUCTION, THE DUAL-CONTROL PENTODE (SECTION 2) IS INTENDED FOR USE AS AN FM DETECTOR AND THE POWER PENTODE (SECTION 1) AS AN AUDIO-FREQUENCY OUTPUT AMPLIFIER IN TELEVISION RECEIVERS.

DIRECT INTERELECTRODE CAPACITANCES

GRID 1 TO PLATE: (I G) TO IP)	0.26	pf
INPUT: IG1 TO (H+ 1K + IG2 + IG3 + I.S.)	11	pf
OUTPUT: IP TO (H + 1K + 1G2 + 1G3 + 1.S.)	12	pf
SECTION 2		
GRID 1 TO PLATE: (2G1 TO 2P)	0.034	pf
GRID 3 TO PLATE: (2 G3 TO 2P)	3.2	pf
GRID 1 TO ALL EXCEPT PLATE: 2G1TO		
(H + 2K + 2G2 + 2G3 + I,S.)	6.5	pf
GRID 3 TO ALL: 2 _{G3} TO (H + 2K + 2G1 + 2G2 + 2P + I.S.)	7.5	pf
GRID 1 TO GRID 3: (2 G1 TO 2G3)	0.24	pf
PLATE TO PLATE: (1P TO 2P)	0,12	pf

CONTINUED ON FOLLOWING PAGE

TUNG-SOL ---

CONTINUED FROM PRECEDING PAGE

HEATER CHARACTERISTICS AND RATINGS

DESIGN MAXIMUM VALUES - SEE EIA STANDARD RS-239

AVERAGE CHARACTERISTICS HEATER WARM-UP TIME	9.8 VOLTS	600 11	MA. SECONDS
LIMITS OF SUPPLIED CURRENT		600 ± 40	MA.
HEATER-CATHODE VOLTAGE	SECTION 1	SECTION 2	
HEATER POSITIVE WITH RESPECT TO CATHODE			
DC COMPONENT	100	100	VOLTS
TOTAL DC AND PEAK	200	200	VOLTS
HEATER NEGATIVE WITH RESPECT TO CATHODE			
TOTAL DC AND PEAK	200	200	VOL TS

MAXIMUM RATINGS DESIGN MAXIMUM VALUES - SEE EIA STANDARD RS-239

	SECTION 1	SECTION 2	
PLATE VOLTAGE	275	330	VOLTS
GRID 2 VOLTAGE	275	SEE RATING CHART	VOLTS
GRID 2 SUPPLY VOLTAGE		330	VOLTS
GRID 3 (SUPPESSOR) VOLTAGE		28	VOLTS
POSITIVE DC GRID 1 VOLTAGE		0	VOLTS
PLATE DISSIPATION	10	1.7	WATTS
GRID 2 DISSIPATION	2.0	1.1	WATTS
GRID 1 CIRCUIT RESISTANCE			
WITH FIXED BIAS	0.25		MEGOHMS
WITH CATHODE BIAS	0.5		MEGOHMS

CHARACTERISTICS AND TYPICAL OPERATION

SECTION 1

PLATE VOLTAGE		250	VOLTS
GRID 2 VOLTAGE		250	VOLTS
GRID 1 VOLTAGE		-8.0	VOLTS
PEAK AF GRID I VOLTAGE		8.0	VOLTS
ZERO-SIGNAL PLATE CURRENT		35	MA.
MAXIMUM-SIGNAL PLATE CURRENT			MA.
ZERO-SIGNAL GRID 2 CURRENT			MA.
MAXIMUM SIGNAL GRID 2 CURRENT			MA.
MAXIMUM-SIGNAL POWER OUTPUT			WATTS
TRANSCONDUCTANCE			MICROMHOS
PLATE RESISTANCE	Approx.	•	OHMS
LOAD RESISTANCE			OHMS
TOTAL HARMONIC DISTORTION	Approx.		PERCENT

CONTINUED ON FOLLOWING PAGE

MEGOHMS

PLATE VOLTAGE	150	VOLTS
GRID 2 VOLTAGE	100	VOLTS
GRID 3 VOLTAGE	0	VOLTS
CATHODE-BIAS RESISTOR	560	OHMS
PLATE CURRENT	1.3	84 A

 CATHODE-BIAS RESISTOR
 560
 OHMS

 PLATE CURRENT
 1.3
 MA.

 GRID 2 CURRENT
 2.1
 MA.

 GRID 1 TRANSCONDUCTANCE
 1,000
 MICROMHOS

 GRID 3 TRANSCONDUCTANCE
 400
 MICROMHOS

GRID 3 TRANSCONDUCTANCE 400
PLATE RESISTANCE Approx. 0.15

GRID 1 VOLTAGE FOR I_b = 30 μ A Approx. -4.5 VOLTS GRID 3 VOLTAGE FOR I_b = 50 μ A Approx. -4.5 VOLTS

